

UNISONIC TECHNOLOGIES CO., LTD

UMY1N

Preliminary

DUAL TRANSISTOR

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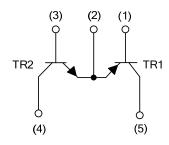
■ DESCRIPTION

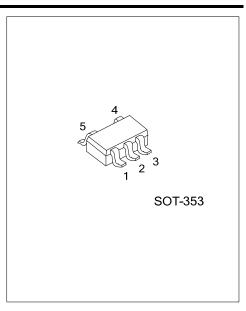
The UTC **UMY1N** is a dual transistor, including a NPN and a PNP which have common emitters. it uses UTC's advanced technology to provide customers with high DC current gain, etc.

■ FEATURES

- * PNP and NPN transistors have common emitters
- * High DC current gain

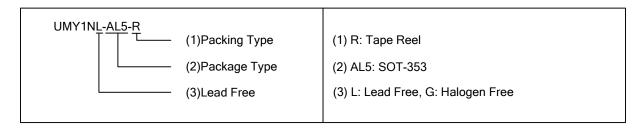
■ EQUIVALENT CIRCUIT



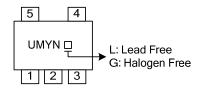


ORDERING INFORMATION

Order Number		Daalaaaa	Pin Assignment				Dooling	
Lead Free	Halogen Free	Package	1	2	3	4	5	Packing
UMY1NL-AL5-R	UMY1NG-AL5-R	SOT-353	B1	E1, E2	B2	C2	C1	Tape Reel



■ MARKING INFORMATION



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

DADAMETED	CVMDOL	RAT	LINUT		
PARAMETER	SYMBOL	TR1	TR2	UNIT	
Collector-Base Voltage	V_{CBO}	-60	60	V	
Collector-Emitter Voltage	V_{CEO}	-50	50	V	
Emitter-Base Voltage	V_{EBO}	-6	7	V	
Continuous Collector Current	Ic	-150	150	mA	
Collector Power Dissipation	Pc	150		mW	
Junction Temperature	TJ	150		°C	
Storage Temperature	T _{STG}	-55~+150		°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
TR1								
Collector-Base Breakdown Voltage	BV_CBO	I _C =-50μA, I _E =0	-60			V		
Collector-Emitter Breakdown Voltage	BV_CEO	$I_C=-1mA$, $I_B=0$	-50			V		
Emitter-Base Breakdown Voltage	BV_{EBO}	I _E =-50μA, I _C =0	-6			V		
Collector Cut-Off Current	I _{CBO}	V _{CB} =-60V, I _E =0			-0.1	μΑ		
Emitter Cut-Off Current	I _{EBO}	V _{EB} =-6V, I _C =0			-0.1	μΑ		
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I_C =-50mA, I_B =-5mA			-0.5	V		
DC Current Gain	h _{FE}	V _{CE} =-6V, I _C =-1mA	120		560			
Transition Frequency	f⊤	V _{CE} =-12V, I _E =-2mA, f=100MHz		140		MHz		
Output Capacitance	C_ob	V _{CB} =-12V, I _E =0, f=1MHz			5	pF		
TR2								
Collector-Base Breakdown Voltage	BV_CBO	$I_{C}=50\mu A, I_{E}=0$	60			V		
Collector-Emitter Breakdown Voltage	BV_CEO	I _C =1mA, I _B =0	50			V		
Emitter-Base Breakdown Voltage	BV_{EBO}	I _E =50μA, I _C =0	7			V		
Collector Cut-Off Current	I _{CBO}	$V_{CB}=60V$, $I_{E}=0$			0.1	μΑ		
Emitter Cut-Off Current	I _{EBO}	V _{EB} =7V, I _C =0			0.1	μΑ		
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	I _C =50mA, I _B =5mA			0.4	V		
DC Current Transfer Ratio	h _{FE}	V _{CE} =6V, I _C =1mA	120		560			
Transition Frequency	f_{T}	V _{CE} =12V, I _E =2mA, f=100MHz		180		MHz		
Output Capacitance	C_ob	V _{CB} =12V, I _E =0, f=1MHz			3.5	pF		

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